RoHS

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**GREEN** 

(5-2008)



## Vishay Semiconductors

## Silicon PIN Photodiode



#### **LINKS TO ADDITIONAL RESOURCES**





#### **DESCRIPTION**

VEMD8081 is a high speed and high sensitive PIN photodiode with enhanced sensitivity for visible light. It is a low profile surface-mount device (SMD) including the chip with a 5.4 mm<sup>2</sup> sensitive area detecting visible and near infrared radiation.

#### **FEATURES**

- Package type: surface-mount
- · Package form: top view



- Radiant sensitive area (in mm2): 5.4
- 0.48 mm low profile package
- Enhanced sensitivity for visible light
- · Suitable for visible and near infrared radiation
- Angle of half sensitivity:  $\varphi = \pm 65^{\circ}$
- Floor life: 168 h, MSL 3, according to J-STD-020
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>



- · High speed photo detector
- Wearables

PRODUCT SUMMARY				
COMPONENT	$I_{ra}$ (μA) at $E_e$ = 1.0 mW/cm², $\lambda$ = 850 nm, $V_R$ = 5.0 $V$	φ (°)	λ <sub>0.1</sub> (nm)	
VEMD8081	33	± 65	350 to 1100	

#### Note

· Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VEMD8081	Tape and reel	MOQ: 5000 pcs, 5000 pcs/reel	Top view		

### Note

MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		$V_{R}$	20	V
Operating temperature range		T <sub>amb</sub>	-40 to +85	°C
Storage temperature range		T <sub>stg</sub>	-40 to +85	°C
Soldering temperature	According to reflow solder profile Fig. 8	T <sub>sd</sub>	260	°C
ESD safety HBM	± 2000 V, 1.5 kΩ, 100 pF, 3 pulses	ESD <sub>HBM</sub>	≥2	kV

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<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 50 mA	V <sub>F</sub>	-	2.3	3.3	V
Reverse dark current	V <sub>R</sub> = 10 V, E = 0	I <sub>ro</sub>	-	0.5	10	nA
Diode capacitance	$V_R = 0 V, f = 1 MHz, E = 0$	C <sub>D</sub>	-	50	-	pF
	$V_R = 3 V, f = 1 MHz, E = 0$	C <sub>D</sub>	-	20	40	pF
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 525 \text{ nm}, V_R = 5 \text{ V}$	I <sub>ra</sub>	15	20	24	μΑ
	$E_e = 1 \text{ mW/cm}^2, \lambda = 850 \text{ nm}, V_R = 5 \text{ V}$	I <sub>ra</sub>	29	33	38	μΑ
Angle of half sensitivity		φ	-	± 65	-	0
Wavelength of peak sensitivity		$\lambda_{p}$	-	840	-	nm
Range of spectral bandwidth		λ <sub>0.1</sub>	-	350 to 1100	-	nm
Rise time	$V_R$ = 10 V, $R_L$ = 50 $\Omega$ , $\lambda$ = 830 nm	t <sub>r</sub>	-	110	-	ns
Fall time	$V_R$ = 10 V, $R_L$ = 50 $\Omega$ , $\lambda$ = 830 nm	t <sub>f</sub>	-	110	-	ns

## **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

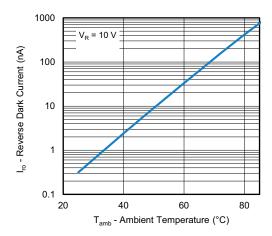


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

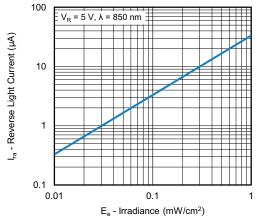


Fig. 3 - Reverse Light Current vs. Irradiance

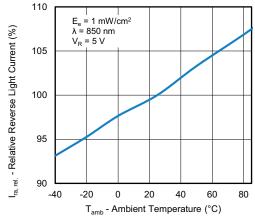


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

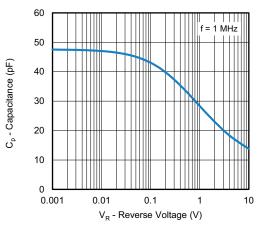


Fig. 4 - Diode Capacitance vs. Reverse Voltage



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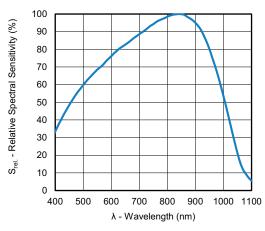


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

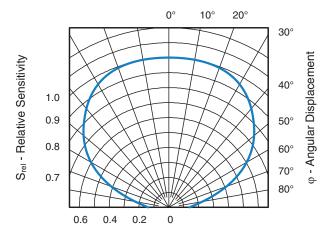
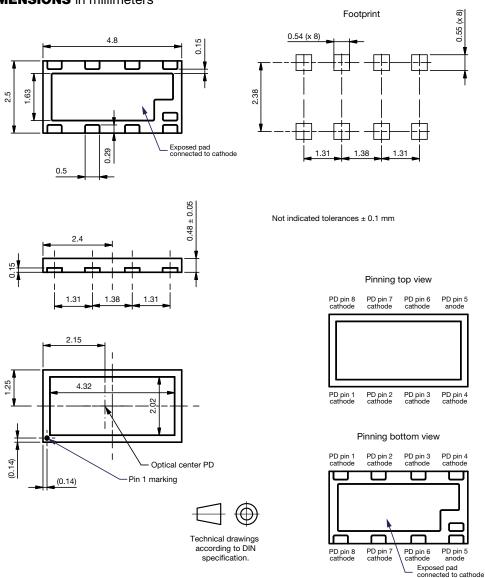


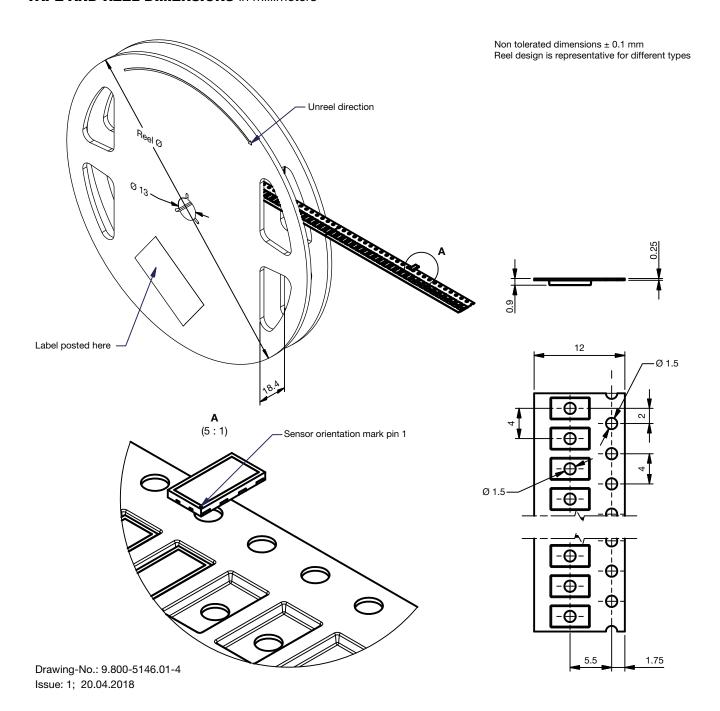
Fig. 6 - Relative Sensitivity vs. Angular Displacement

### **PACKAGE DIMENSIONS** in millimeters



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### TAPE AND REEL DIMENSIONS in millimeters





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#### **SOLDER PROFILE**

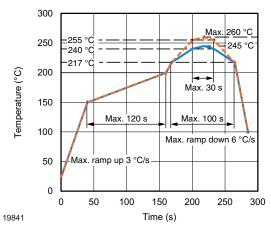


Fig. 7 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020D

### **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 3

Floor life: 168 h

Conditions:  $T_{amb}$  < 30 °C, RH < 60 %

#### **DRYING**

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-033D or recommended conditions:

192 h at 40 °C (+ 5 °C), RH < 5 %

or

96 h at 60 °C (+ 5 °C), RH < 5 %



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